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View Online at https://aerobasegroup.com/nsn/5961-01-322-9505 **Inclosure Material:** Glass **Overall Length:** 0.795 inches **Terminal Length:** 0.700 inches **Overall Height:** 0.255 inches **Overall Width:** 0.540 inches **Mounting Facility Quantity:** Joint Electronic Device Engineering Council/jedec/case Outline Designation: To-254 **Component Name And Quantity:** 2 semiconductor device diode **Mounting Method:** Terminal and unthreaded hole **Features Provided:** Hermetically sealed case **Criticality Code Justification:** Zzzy **Semiconductor Material:** Silicon all semiconductor device diode Voltage Rating In Volts Per Characteristic: 45.0 working peak reverse voltage all semiconductor device diode **Current Rating Per Characteristic:** 30.00 amperes forward current, average absolute all semiconductor device diode and 25.00 amperes source cutoff current preset all semiconductor device diode **Maximum Operating Tempurature Per Measurement Point:** 150.0 degrees celsius ambient air **Special Features:** Item must comply with requirements of defense supply center columbus production standard lo4304 **Terminal Type And Quantity:** 3 uninsulated wire lead **Reference Number Differentiating Characteristics:** Breference number differentiating material will be in accordance with naval inventory control point activity hx quality control. Manufacturing and testing specifications available at the dla icp. Shelf Life: N/a **Unit Of Measure:**

No

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